DESCRIPTION

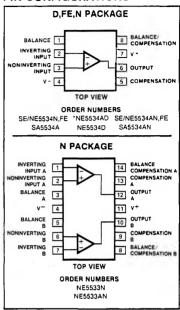
The 5533/5534 are dual and single highperformance low noise operational amplifiers. Compared to other operational amplifiers, such as TL083, they show better noise performance, improved output drive capability and considerably higher small-signal and power bandwidths.

This makes the devices especially suitable for application in high quality and professional audio equipment, in instrumentation and control circuits and telephone channel amplifiers. The op amps are internally compensated for gain equal to, or higher than, three. The frequency response can be optimized with an external compensation capacitor for various applications (unity gain amplifier, capacitive load, slew-rate, low overshoot, etc.) If very low noise is of prime importance, it is recommended that the 5533A/5534A version be used which has guaranteed noise specifications.

FEATURES

- Small-signal bandwidth: 10MHz
- Output drive capability: 600Ω , 10V (rms) at $V_s = \pm 18V$
- Input noise voltage: 4nV/√Hz
- DC voltage gain: 100000
- . AC voltage gain: 6000 at 10kHz
- Power bandwidth: 200kHz
- Slew-rate: 13V/μs
- Large supply voltage range: ±3 to ±20V

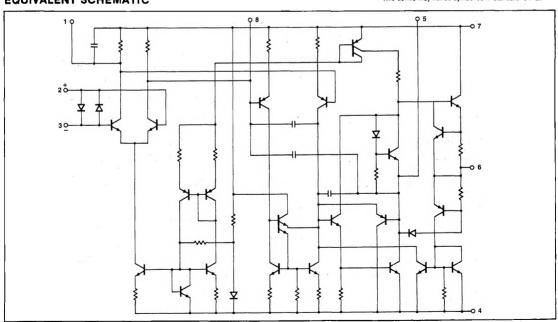
PIN CONFIGURATIONS



*NOTE:

This device may not be symbolled in standard format.

EQUIVALENT SCHEMATIC



ABSOLUTE MAXIMUM RATINGS

	PARAMETER	RATING	UNIT
v _s	Supply voltage	± 22	٧
ViN	Input voltage	± V supply	V
VDIFF	Differential input voltage ¹	± 0.5	V
TA	Operating temperature range		
	SE5534/5534A	- 55 to + 125	°C
	NE5533/5533A/5534/5534A	0 to +70	•c
TSTG	Storage temperature	- 65 to + 150	°C
	Junction temperature	150	•c
T _J P _D	Power dissipation at 25°C ²		
J	5533N, 5534N, 5534FE	800	mW
	Output short circuit duration ³	indefinite	
	Lead temperature (soldering, 10 sec)	300	°C

- 1. Diodes protect the inputs against over-voltage. Therefore, unless current-limiting resistors are used, large currents will flow if the differential input voltage exceeds 0.6V. Maximum current should be limited to ±10mA.
- 2. For operation at elevated temperature, derate packages based on the following junction-to-ambient thermal resistances:
- 8-pin ceramic (FE) 140° C/W
- 14-pin ceramic (F) 110°C/W 8-pin plastic (N) 162° C/W
- 14-pin plastic (N) 150° C/W
- 3. Output may be shorted to ground at $V_S = \pm 15V$, $T_A = 25^{\circ}C$. Temperature and/or supply voltages must be limited to ensure dissipation rating is not exceeded.

DC ELECTRICAL CHARACTERISTICS $T_A = 25 \,^{\circ}\text{C}$, $V_S = \pm 15 \text{V}$ unless otherwise specified.^{1,2}

	PARAMETER	TEST CONDITIONS	SE5534/5534A			NE5533/5533A 5534/5534A			UNIT
			Min	Тур	Max	Min	Тур	Max	
V _{OS} ΔV _{OS} /Δ1	Offset voltage	Over temperature		0.5 5	2		0.5 5	4 5	mV mV μV/°C
l _{os} Δl _{os} /ΔT	Offset current	Over temperature		10. 200	200 500		20 200	300 400	nA nA pA/°C
I _B ΔΙ _Β /ΔΤ	Input current	Over temperature		400 5	800 1500		500 5	1500 2000	nA nA nA/°C
Icc	Supply current Per op amp	Over temperature		4	6.5 9		4	8 10	mA mA
V _{CM} CMRR PSRR	Common mode input range Common mode rejection ratio Power supply rejection ratio		± 12 80	± 13 100 10	50	± 12 70	± 13 100 10	100	V dΒ μV/V
A _{VOL}	Large signal voltage gain	$R_L \ge 600\Omega$, $V_O = \pm 10V$ Over temperature	50 25	100		25 15	100		V/mV V/mV
V _{OUT}	Output swing 5534 only	$R_L \ge 600\Omega$ Over temperature $R_L \ge 600\Omega$, $V_S = \pm 18V$ $R_L \ge 2k\Omega$ Over Temperature	± 12 ± 10 ± 15 ± 13 ± 12	± 13 ± 12 ± 16 ± 13.5 ± 12.5		± 12 ± 10 ± 15 ± 13 ± 12	± 13 ± 12 ± 16 ± 13.5 ± 12.5		V V V
R _{IN}	Input resistance		50	100		30	100		kΩ
I _{sc}	Output short circuit current			38			38		mA

^{1.} For NE5533/5533A/5534/5534A, T_{MIN} = 0°C, T_{MAX} = 70°C 2. For SE5534/5534A, T_{MIN} = -55°C, T_{MAX} = + 125°C

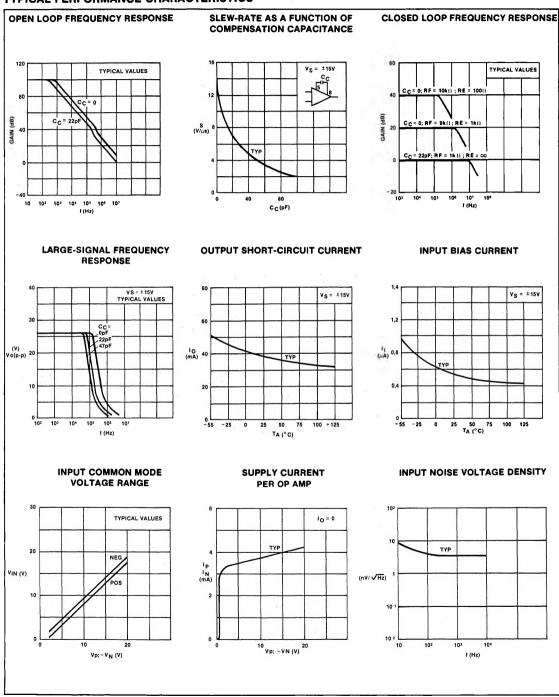
AC ELECTRICAL CHARACTERISTICS $T_A = 25^{\circ}\text{C}$, $V_S = \pm 15\text{V}$ unless otherwise specified.

	PARAMETER	TEST CONDITIONS	SE5534/5534A			NE5533/5533A 5534/5534A			UNIT
			Min	Тур	Max	Min	Тур	Max	
Rоит	Output resistance	$A_V = 30 dB$ closed loop $f = 10 kHz$, $R_L = 600 \Omega$, $C_C = 22 pF$		0.3			0.3		Ω
Transien	t response	Voltage follower, V _{IN} = 50mV R _L = 600Ω, C _C = 22pF, C _L = 100pF							
TR	Rise time Overshoot			20 20			20 20		ns %
Transien	t response	$V_{IN} = 50 \text{mv}, R_L = 600 \Omega$ $C_C = 47 \text{pF}, C_L = 500 \text{pF}$							
TR	Rise time Overshoot			50 35			50 35		ns %
AC	Gain	$f = 10kHz, C_C = 0$ $f = 10kHz, C_C = 22pF$		6 2.2			6 2.2		V/mV V/mV
	Gain bandwidth product	C _C = 22pF, C _L = 100pF		10			10		mHz
	Slew rate	C _C = 0 C _C = 22pF		13 6			13 6		V/μS V/μS
	Power bandwidth	$V_{OUT} = \pm 10V$, $C_C = 0$ $V_{OUT} = \pm 10V$, $C_C = 22pF$ $V_{OUT} = \pm 14V$, $R_L = 600\Omega$ $C_C = 22pF$, $V_{CC} = \pm 18V$		200 95 70			200 95 70		kHz kHz kHz

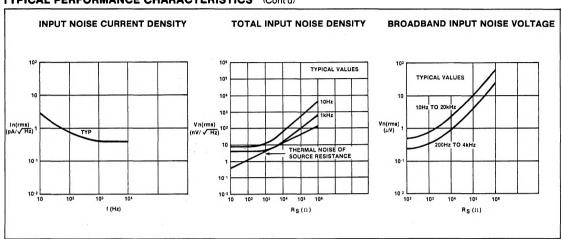
ELECTRICAL CHARACTERISTICS $T_A = 25^{\circ}C$, $V_S = \pm 15V$ unless otherwise specified.

	TEST CONDITIONS	5533/5534			5533A/5534A			
PARAMETER		Min	Тур	Max	Min	Тур	Max	UNIT
Input noise voltage	f _O = 30Hz f _O = 1kHz		7 4			5.5 3.5	7 4.5	nV/√Hz nV/√Hz
Input noise current	f _O = 30Hz f _O = 1kHz		2.5 0.6			1. 5 0.4		pA/√Hz pA/√Hz
Broadband noise figure	$f = 10Hz - 20kHz$, $R_S = 5k\Omega$					0.9		dB
Channel separation	$f = 1 \text{kHz}, R_S = 5 \text{k}\Omega$		110			110		dB

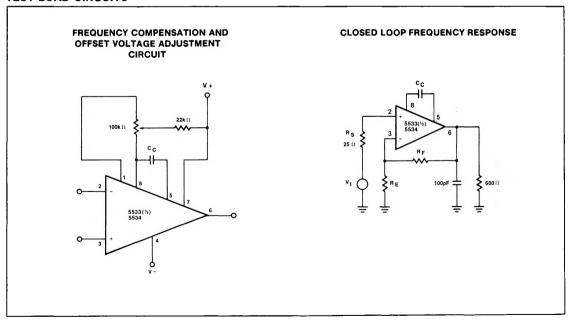
TYPICAL PERFORMANCE CHARACTERISTICS



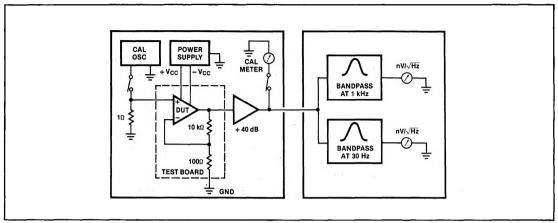
TYPICAL PERFORMANCE CHARACTERISTICS (Cont'd)



TEST LOAD CIRCUITS



NOISE TEST BLOCK DIAGRAM



^{*}For additional information, consult the Applications Section.